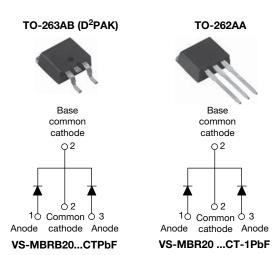


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High Performance Schottky Rectifier, 2 x 10 A



PRODUCT SUMMARY					
Package	TO-263AB (D ² PAK), TO-262AA				
I _{F(AV)}	2 x 10 A				
V_{R}	80 V, 90 V, 100 V				
V _F at I _F	0.70 V				
I _{RM} max.	15 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	8.0 mJ				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Center tap D²PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform (per device)	20	А			
I _{FRM}	$T_C = 133 ^{\circ}\text{C} \text{ (per leg)}$	20] ^			
V _{RRM}		80 to 100	V			
I _{FSM}	$t_p = 5 \mu s sine$	850	Α			
V _F	10 A _{pk} , T _J = 125 °C	0.70	V			
TJ	Range	-65 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL			VS-MBRB20100CTPbF VS-MBR20100CT-1PbF	UNITS	
Maximum DC reverse voltage	V_R	80	90	100	V	
Maximum working peak reverse voltage	V_{RWM}	00	90	100	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average per leg		T _C = 133 °C, rated V _B	10		
forward current per device	I _{F(AV)}	TC = 133 C, Tated V _R	20		
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 133 °C	20		
Non repetitive peak aurea aureant		5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated V _{RRM} applied	850	Α	
Non-repetitive peak surge current	IFSM	Surge applied at rated load conditions half wave, single phase, 60 Hz	150		
Peak repetitive reverse surge current	I _{RRM}	2.0 μs, 1.0 kHz	0.5		
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25$ °C, $I_{AS} = 2$ A, L = 12 mH	24	mJ	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		10 A	T _{.1} = 25 °C	0.80	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.95	
Maximum forward voltage drop	V FM ('')	10 A	- T _{.1} = 125 °C	0.70	
		20 A	- 1j = 125 C	0.85	
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.10	- mA
reverse current		T _J = 125 °C	hated DC voltage	6	
Threshold voltage	V _{F(TO)}	T T maximum		0.433	V
Forward slope resistance	r _t	i j = i j maximum	$T_J = T_J$ maximum		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	400	pF	
Typical series inductance	L _S	Measured from top of ter	minal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction tempera	ature range	TJ		-65 to +150	°C	
Maximum storage tempera	ture range	T _{Stg}		-65 to +175	°C	
Maximum thermal resistan junction to case per leg	ce,	R _{thJC}	DC operation	2.0		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W	
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation	50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm	
Mounting torque -	maximum		Non-iubricated tilleads		(lbf · in)	
Marking davise			Case style D ² PAK	MBRB2	0100CT	
Marking device			Case style TO-262	MBR201	100CT-1	

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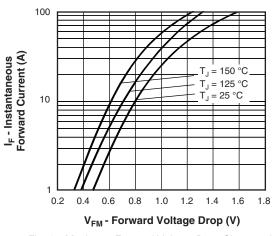


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

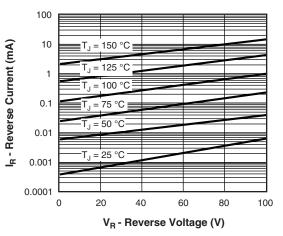


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

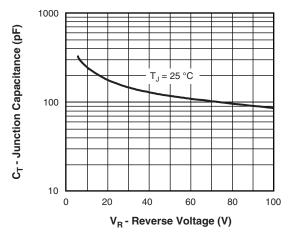


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

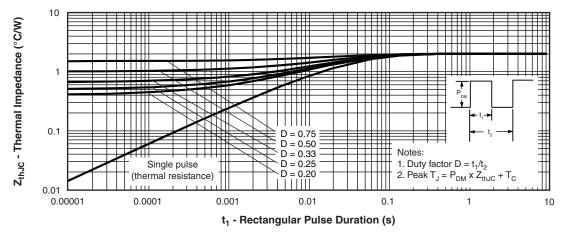


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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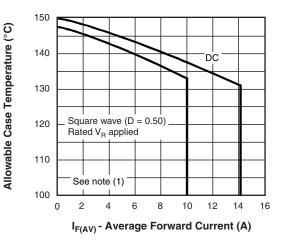


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

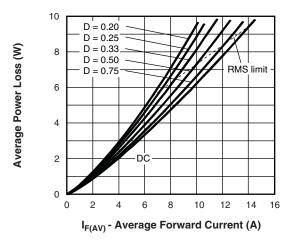


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

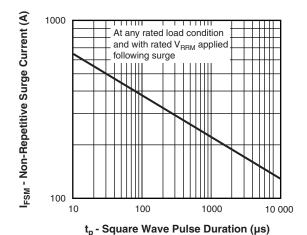


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

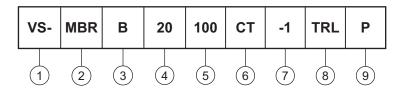
Note

(1) Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Essential part number
- B = D²PAK
 None
 None = TO-262
 | 7 | = -1
- Current rating (20 = 20 A) 80 = 80 V 5 - Voltage ratings 90 = 90 V
- 6 CT = essential part number
- 7 • None = D²PAK 3 = B • -1 = TO-262 3 None
- None = tube (50 pieces)
 TRL = tape and reel (left oriented for D²PAK only)
 - TRR = tape and reel (right oriented for D²PAK only)
- 9 • PbF = lead (Pb)-free (for TO-262 and D²PAK tube)
 - P = lead (Pb)-free (for D²PAK TRR and TRL)

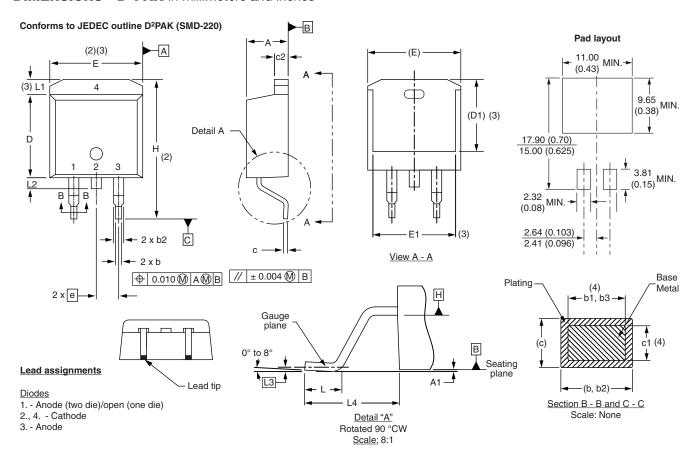
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95014				
Part marking information	www.vishay.com/doc?95008				
Packaging information	www.vishay.com/doc?95032				



Vishay Semiconductors

D²PAK, TO-262

DIMENSIONS - D²PAK in millimeters and inches



	MILLIMETERS		INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INCHES		NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100 BSC			
Н	14.61	15.88	0.575	0.625		
L	1.78	2.79	0.070	0.110		
L1	-	1.65	-	0.066	3	
L2	1.27	1.78	0.050	0.070		
L3	0.25	BSC	0.010	BSC		
L4	4.78	5.28	0.188	0.208		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

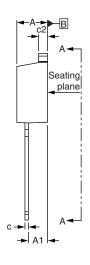
(7) Outline conforms to JEDEC outline TO-263AB

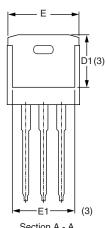
D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches

Modified JEDEC outline TO-262 (Datum A) - (2) (3) (3)D -3 x b2 3 x b



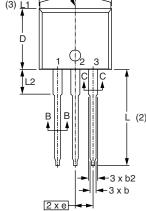




Section A - A

b1, b3

Section B - B and C - C Scale: None





Lead assignments



Diodes 1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode

CVMDOL	MILLIMETERS		INC	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	2.54 BSC		0 BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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